

## **KSA992**

### **Audio Frequency Low Noise Amplifier**

Complement to KSC1845



### 1. Emitter 2. Collector 3. Base

# **PNP Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	-120	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-120	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-50	mA
I <sub>B</sub>	Base Current	-10	mA
P <sub>C</sub>	Collector Power Dissipation	500	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -120V, I_{E} = 0$			-50	nA
I <sub>CEO</sub>	Collector Cur-off Current	V <sub>CE</sub> = -100V, I <sub>B</sub> =0			-1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ = -5mA, $I_{C}$ =0			-50	nA
h <sub>FE1</sub>	DC Current Gain	$V_{CE}$ = -6V, $I_{C}$ = -0.1mA $V_{CE}$ = -6V, $I_{C}$ = -1mA	150 200	500 500	800	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE}$ = -6V, $I_{C}$ = -1mA	-0.55	-0.61	-0.65	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1mA		-0.09	-0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE}$ = -6V, $I_{C}$ = -1mA	50	100		MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB}$ = -30V, $I_{E}$ =0, f=1MHz		2	3	pF
NV	Noise Voltage	$V_{CE} = -5.0V, I_{C} = -1.0mA,$ $R_{G} = 100KW, G_{V} = 80dB,$ f = 10Hz  to  1.0KHz		25	40	mV

# h<sub>FE2</sub> Classification

Classification	Р	F	E
h <sub>FE2</sub>	200 ~ 400	300 ~ 600	400 ~ 800

# **Typical Characteristics**

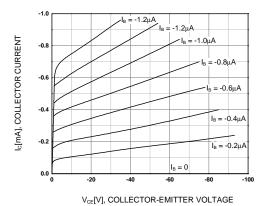


Figure 1. Static Characteristic

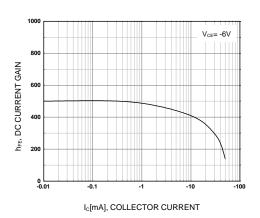


Figure 3. DC current Gain

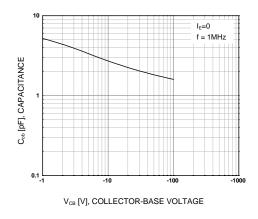


Figure 5. Collector Output Capacitance

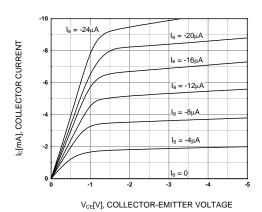


Figure 2. Static Characteristic

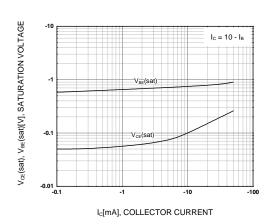


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

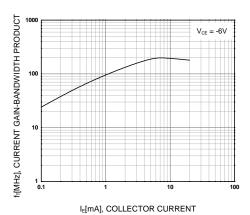


Figure 6. Current Gain Bandwidth Product

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# Typical Characteristics (Continued)

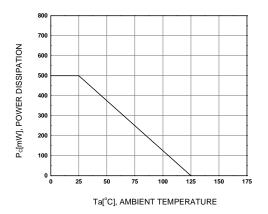
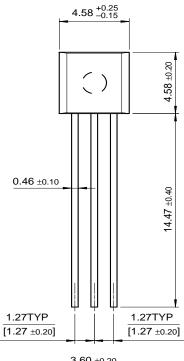
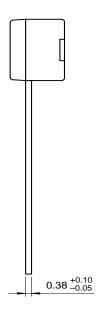


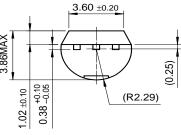
Figure 7. Power Derating

# **Package Dimensions**

TO-92







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FACT™	ImpliedDisconnect™	OCXPro™	μSerDes™	UltraFET <sup>®</sup>
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